

Single N-channel 60 V, 4.5 mOhm logic level MOSFET in LFPAK56 using Enhanced SOA technology 7 April 2022

Product data sheet

1. General description

Single, logic level, N-channel MOSFET in LFPAK56 using Application specific (ASFET) Enhanced SOA technology. This product has been designed and qualified to AEC-Q101 for use in linear mode in airbag applications.

2. Features and benefits

- Fully automotive qualified to AEC-Q101 at 175 °C
- Enhanced SOA technology for improved linear mode performance
- LFPAK copper clip package technology:
 - · High robustness and current handling capability
 - Gull wing leads for easy AOI inspection and exceptional board level reliability •

3. Applications

- 12 V automotive systems
- Airbag squib voltage regulator MOSFET

4. Quick reference data

Table 1 Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	-	60	V
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>	[1]	-	-	125	А
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>		-	-	238.4	W
Static chara	acteristics				_		
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 25 A; T _j = 25 °C; Fig. 13		2.5	3.6	4.5	mΩ
Dynamic ch	naracteristics				_		
Q _{GD}	gate-drain charge	$\label{eq:ID} \begin{array}{l} I_D = 25 \text{ A}; \ V_{DS} = 48 \text{ V}; \ V_{GS} = 4.5 \text{ V}; \\ T_j = 25 \ ^\circ\text{C}; \ \overline{\text{Fig. 15}}; \ \overline{\text{Fig. 16}} \end{array}$		-	22	44	nC

125 A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, [1] thermal design and operating temperature.

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5. Pinning information

Table 2	. Pinning info	rmation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source	mb	
2	S	source		D
3	S	source	a	
4	G	gate		G_UEA)
mb	D	mounting base; connected to drain	LFPAK56; Power- SO8 (SOT669)	mbb076 S

6. Ordering information

Table 3. Ordering information

Type number Package					
	Name	Description	Version		
BUK9Y7R0-60EL	LFPAK56; Power-SO8	plastic, single-ended surface-mounted package; 4 terminals	SOT669		

7. Marking

Table 4. Marking codes	
Type number	Marking code
BUK9Y7R0-60EL	97E060L

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Tj = 25 °C unless otherwise stated.

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	60	V
V _{GS}	gate-source voltage	DC; T _j ≤ 175 °C		-10	10	V
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>		-	238.4	W
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>	[1]	-	125	А
		V _{GS} = 10 V; T _{mb} = 100 °C; <u>Fig. 2</u>		-	108	А
I _{DM}	peak drain current	pulsed; $t_p \le 10 \ \mu$ s; $T_{mb} = 25 \ ^{\circ}$ C; <u>Fig. 3;</u> Fig. 4		-	612	A
T _{stg}	storage temperature			-55	175	°C
Tj	junction temperature			-55	175	°C
Source-drai	n diode				-	
Is	source current	T _{mb} = 25 °C		-	125	А
I _{SM}	peak source current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^{\circ}C$		-	612	А
Avalanche r	uggedness					
E _{DS(AL)S}	non-repetitive drain- source avalanche energy	$ \begin{array}{l} {\sf I}_{\sf D} = 73 \; {\sf A}; \; {\sf V}_{sup} \leq \; 60 \; {\sf V}; \; {\sf R}_{\sf GS} = 50 \; \Omega; \\ {\sf V}_{\sf GS} = 10 \; {\sf V}; \; {\sf T}_{j(init)} = 25 \; {^\circ}{\sf C}; \; unclamped; \\ {\sf t}_p = 87 \; \mu s; \; \underline{{\sf Fig. 5}} \end{array} $	[2] [3]	-	261	mJ

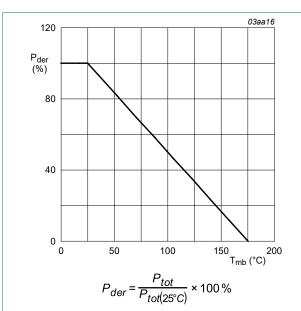
Symbol	Parameter	Conditions		Min	Max	Unit
I _{AS}	non-repetitive avalanche current	$V_{sup} \le 60 \text{ V}; V_{GS} = 10 \text{ V}; T_{j(init)} = 25 \text{ °C}; R_{GS} = 50 \Omega; Fig. 5$	[2] [3] [4]	-	73	A

[1] 125 A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

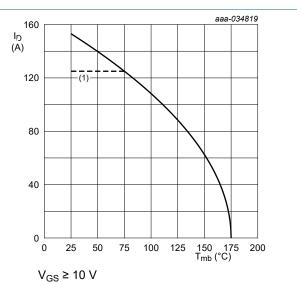
[2] Single-pulse avalanche rating limited by maximum junction temperature of 175 °C.

[3] Refer to application note AN10273 for further information.

[4] Protected by 100% test.

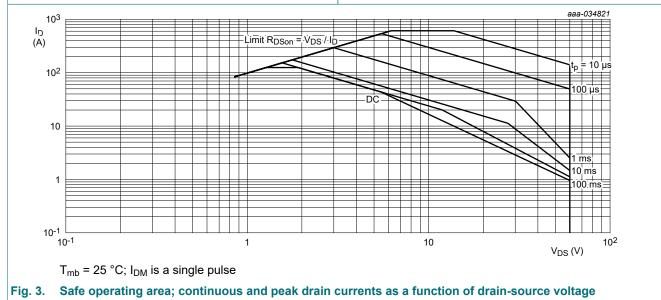


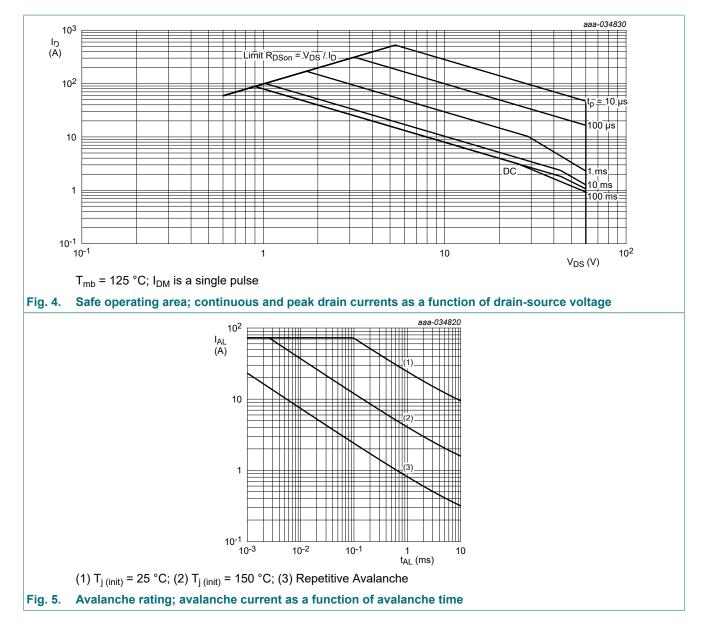




(1) 125 A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

Fig. 2. Continuous drain current as a function of mounting base temperature

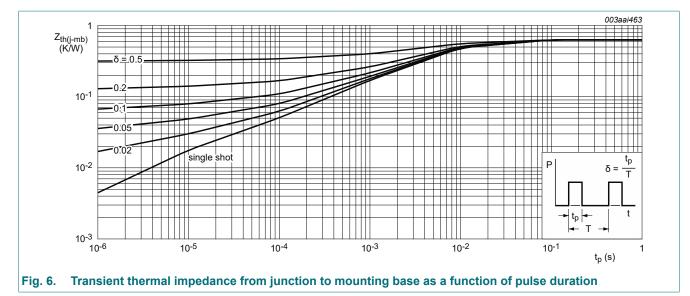




9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	<u>Fig. 6</u>	-	0.56	0.63	K/W

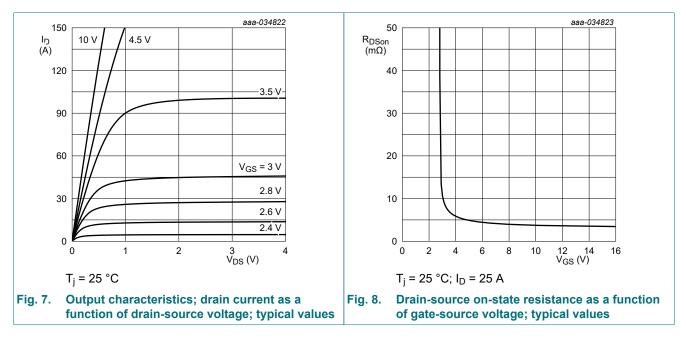


10. Characteristics

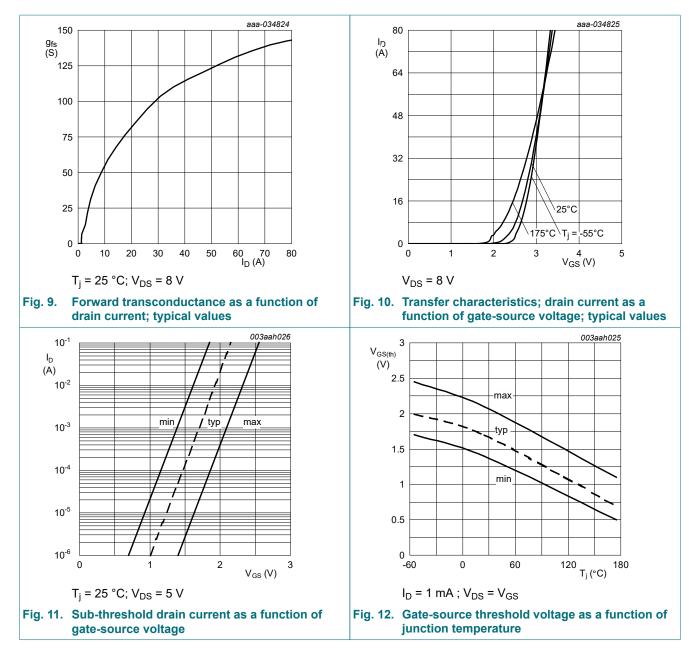
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	octeristics	· · ·				
V _{(BR)DSS}	drain-source	I _D = 250 μA; V _{GS} = 0 V; T _j = 25 °C	60	66	-	V
	breakdown voltage	I _D = 250 μA; V _{GS} = 0 V; T _j = -40 °C	-	62	-	V
		I _D = 250 μA; V _{GS} = 0 V; T _j = -55 °C	54	61.7	-	V
V _{GS(th)}	gate-source threshold voltage	I _D = 1 mA; V _{DS} =V _{GS} ; T _j = 25 °C; <u>Fig. 11;</u> <u>Fig. 12</u>	1.4	1.75	2.1	V
		I _D = 1 mA; V _{DS} =V _{GS} ; T _j = -55 °C; <u>Fig. 12</u>	-	-	2.45	V
1		I _D = 1 mA; V _{DS} =V _{GS} ; T _j = 175 °C; Fig. 12	0.5	-	-	V
I _{DSS}	drain leakage current	V _{DS} = 60 V; V _{GS} = 0 V; T _j = 25 °C	-	0.032	1	μA
		V _{DS} = 60 V; V _{GS} = 0 V; T _j = 175 °C	-	91	500	μA
I _{GSS}	gate leakage current	V _{GS} = 10 V; V _{DS} = 0 V; T _j = 25 °C	-	2	100	nA
		V _{GS} = -10 V; V _{DS} = 0 V; T _j = 25 °C	-	2	100	nA
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 25 A; T _j = 25 °C; Fig. 13	2.5	3.6	4.5	mΩ
		V _{GS} = 10 V; I _D = 25 A; T _j = 105 °C; Fig. 14	3.8	5.7	7.3	mΩ
		V _{GS} = 10 V; I _D = 25 A; T _j = 125 °C; Fig. 14	4.2	6.3	8.1	mΩ
		V _{GS} = 10 V; I _D = 25 A; T _j = 175 °C; Fig. 14	5.2	7.8	10.3	mΩ
		V _{GS} = 4.5 V; I _D = 25 A; T _j = 25 °C; Fig. 13	3.6	5.2	7	mΩ
		V _{GS} = 4.5 V; I _D = 25 A; T _j = 105 °C; Fig. 14	5.4	8	11	mΩ
		V _{GS} = 4.5 V; I _D = 25 A; T _j = 125 °C; Fig. 14	5.9	8.8	12.2	mΩ
		V _{GS} = 4.5 V; I _D = 25 A; T _j = 175 °C; Fig. 14	7.2	10.9	15.4	mΩ

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _G	gate resistance	f = 1 MHz; T _j = 25 °C		-	2.39	-	Ω
Dynamic cl	haracteristics						
Q _{G(tot)}	total gate charge	$ I_D = 25 \text{ A}; \text{ V}_{DS} = 48 \text{ V}; \text{ V}_{GS} = 4.5 \text{ V}; \\ T_j = 25 \text{ °C}; \text{ Fig. 15}; \text{ Fig. 16} $		-	53	74	nC
		$\label{eq:ID} \begin{array}{l} I_D = 25 \; \text{A}; \; V_{DS} = 48 \; \text{V}; \; V_{GS} = 10 \; \text{V}; \\ T_j = 25 \; ^\circ\text{C}; \; \overline{\text{Fig. 15}; \; \overline{\text{Fig. 16}}} \end{array}$		-	109	152	nC
Q _{GS}	gate-source charge	$I_{D} = 25 \text{ A}; V_{DS} = 48 \text{ V}; V_{GS} = 4.5 \text{ V};$ $T_{j} = 25 \text{ °C}; \frac{\text{Fig. 15}; \text{Fig. 16}}{\text{V}_{DS}} = 25 \text{ V}; V_{GS} = 0 \text{ V}; \text{ f} = 1 \text{ MHz};$		-	14	22	nC
Q _{GD}	gate-drain charge	T _j = 25 °C; <u>Fig. 15;</u> <u>Fig. 16</u>		-	22	44	nC
C _{iss}	input capacitance	V _{DS} = 25 V; V _{GS} = 0 V; f = 1 MHz; T _j = 25 °C; <u>Fig. 17</u>		-	5948	8327	pF
C _{oss}	output capacitance			-	517	620	pF
C _{rss}	reverse transfer capacitance			-	280	383	pF
t _{d(on)}	turn-on delay time	V _{DS} = 25 V; V _{GS} = 0 V; f = 1 MHz;		-	27	-	ns
t _r	rise time			-	67	-	ns
t _{d(off)}	turn-off delay time	-		-	72	-	ns
t _f	fall time	-		-	53	-	ns
9fs	transfer conductance	V _{DS} = 8 V; I _D = 25 A; T _j = 25 °C; <u>Fig. 9</u>		-	90	-	S
Source-dra	ain diode						
V _{SD}	source-drain voltage	I_{S} = 25 A; V_{GS} = 0 V; T_{j} = 25 °C; <u>Fig. 18</u>		-	0.81	1	V
t _{rr}	reverse recovery time	$I_{S} = 25 \text{ A}; \text{ d}I_{S}/\text{d}t = -100 \text{ A}/\mu\text{s}; \text{ V}_{GS} = 0 \text{ V};$		-	32	-	ns
Q _r	recovered charge	V _{DS} = 30 V; T _j = 25 °C; <u>Fig. 19</u>	[1]	-	38.5	-	nC

[1] includes capacitive recovery

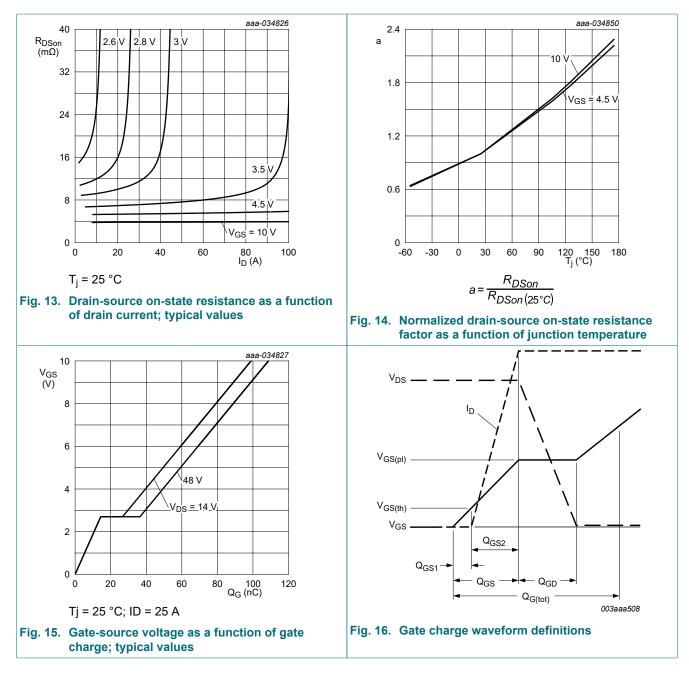


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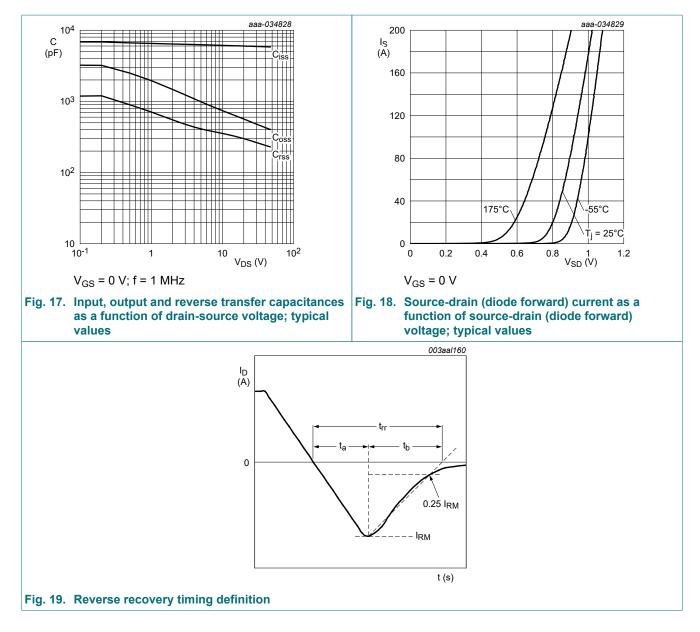


Product data sheet

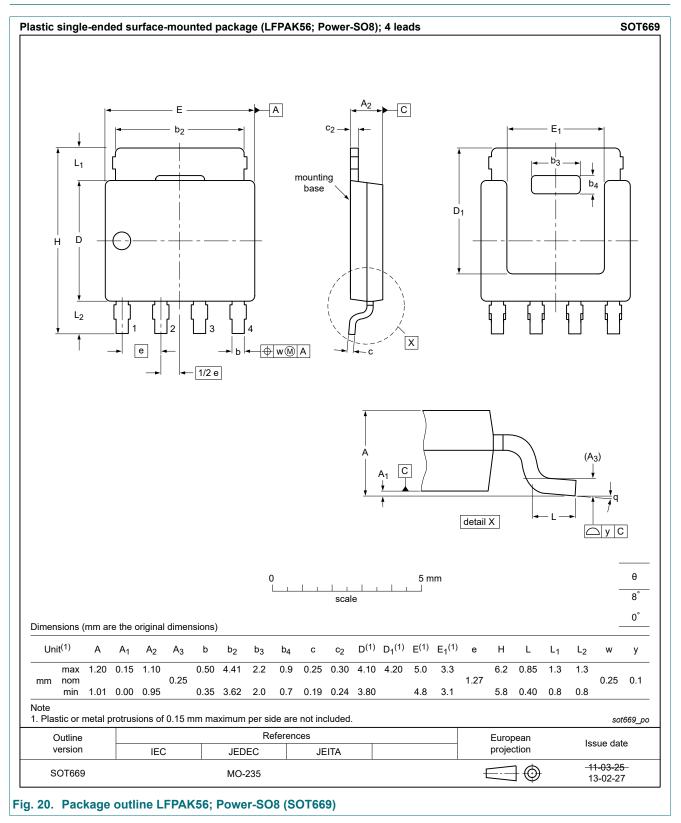
Single N-channel 60 V, 4.5 mOhm logic level MOSFET in LFPAK56 using Enhanced SOA technology



Single N-channel 60 V, 4.5 mOhm logic level MOSFET in LFPAK56 using Enhanced SOA technology



11. Package outline



12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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